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Influence of water concentration on the growth kinetics and M/SC selectivity of individual SWCNTs from in situ optical microscopy E. A. Zamudio Medina ^{1,*}, V. Pimonov ¹, S. Tahir ¹, E. Anglaret ¹, V. Jourdain

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Introduction

Chiral selective synthesis of SWCNTs has been one of the main drawbacks that have hindered their application, specially in electronics, where high chiral purity is required. The control of chirality, length and density of synthesized CNTs has been studied by varying synthesis parameters, such as catalyst systems, temperature, pressure, carbon precursors and etchants [1]. Here, we studied the influence of pressure of the etchant (water) on the SWCNT growth kinetics during alcohol catalytic chemical vapor deposition (CVD). A water-assisted CVD coupled with an *in situ* optical imaging set-up was used. Methods

Growth kinetics



Homodyne polarization microscopy was used for imaging long aligned individual SWCNTs during their growth, as reported in [2].



114 s

164 s



Figure 2. SEM pictures a) before and b) after electrodes deposition.

a) Metallic NTs





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Figure 3. Distributions of growth rates, growth lifetime and lifetime versus linear growth rates for a) 149 ppm, b) 360 ppm, c) 704 ppm and d)1219 ppm of water. The confidence interval for the mean growth rates was set to 95%.

Etching kinetics

| Water | Etching | Mean etching | Mean etching |
|---------------|----------------|-------------------|--------------|
| concentration | Probability(%) | rate (mm/s) | time (s) |
| 149 ppm | 7 | 0.296 ± 0.015 | 17 |
| | | (sd = 0.153) | (sd=15) |
| 360 ppm | 16 | 0.192 ± 0.060 | 18 |
| | | (sd= 0,097) | (sd=23) |
| 704 ppm | 30 | 0,460 ± 0.102 | 23 |
| | | (sd= 0,239) | (sd = 16) |
| 1219 ppm | 26 | 0.416 ± 0.136 | 19 |
| | | (sd= 0.278) | (sd =15) |

Conclusions and perspectives



Figure 4. Snapshots of growth and etching of a CNT

M/SC contrast enhanced after electrodes deposition, facilitating the correlation of growth kinetics with metallicity.

When increasing water concentration

- The average growth rate increase, as well as the broadness of the distribution
 - New fast rates appear: new type of nanotubes? New type of edges? New type of catalyst particles?
- Growth lifetime (for linear growth NTs) decreases
 - The probability of spontaneous switch from growth to etching tends to increase.

References

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